



# GBJ15005 - GBJ1510/G

# Single Phase 15Amp Glass passivated Bridge Rectifiers

#### Features

- · Glass passivated die construction
- Low forward voltage drop
- High current capability
- High surge current capability
- Plastic material-UL flammability 94V-0
- The G suffix is uses for photoresist chip, otherwise it is a knife scraping chip

#### **MECHANICAL DATA**

- Case: Molded plastic, GBJ
- Terminals: Plated Leads Solderable perMIL-STD-202, Method 208
- Polarity: As Marked on Case
- Mounting Position: Any
- Marking: Type Number
- · Lead Free: For RoHS / Lead Free Version

#### Maximum Ratings And Electrical Characteristics (@T<sub>A</sub>=25°C unless otherwise noted)

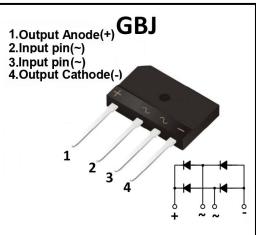
Symbol	Parameter	GBJ	GBJ	GBJ	GBJ	GBJ	GBJ	GBJ	Unit
		15005	1501	1502	1504	1506	1508	1510	
V <sub>RRM</sub>	repetitive peak reverse voltage	50	100	200	400	600	800	1000	
V <sub>RWM</sub>	Working Peak Reverse Voltage	50	100	200	400	600	800	1000	V
V <sub>RMS</sub>	RMS voltage	35	70	140					
V <sub>DC</sub>	DC blocking voltage	50	100	200	400	600	800	1000	
IF <sub>AV</sub>	Average Rectified Output	15.0							A
	Current (Note 1)@T <sub>C</sub> =90°C	13.0							
I <sub>FSM</sub>	Peak forward surge current, 8.3ms single	220						А	
	half sine-wave								
I <sup>2</sup>	I <sup>2</sup> <sub>t</sub> Rating for fusing (t<8.3ms)	200.86					A <sub>S</sub> <sup>2</sup>		
V <sub>FM</sub>	Forward Voltage @IF=7.5A	1.0						V	
	per element @IF=15A	1.10							
	Peak Reverse Current@T <sub>A</sub> =25°C	5.0						uA	
I <sub>R</sub>	at rated DC blocking voltage $@T_A=125^{\circ}C$	500							
CJ	Typical junction capacitance	60				pF			
R <sub>θJA</sub>	Between junction and ambient, Without heatsink	12					°C/W		
R <sub>θJC</sub>	Between junction and case, With heatsink	1.2							
TJ	Operation Temperature Range	-55 to +150					°C		
T <sub>STG</sub>	Storage Temperature Range	-55 to +150							

Note:(1)Thermal resistance from junction to case per element. Unit mounted on 75x75x1.6mm aluminum plate heat sink. BORN SEMICONDUCTOR , INC. ALL

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Mechanical Data







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#### **Ratings And Characteristic Curves**

#### Figure 1: Output Current Derating Curve

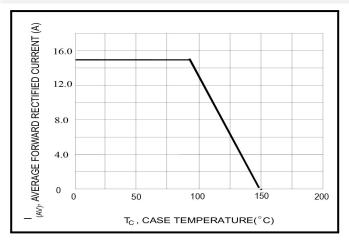
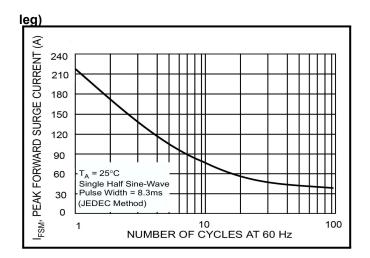
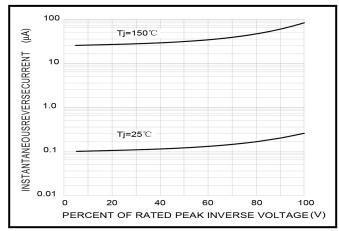


Figure 3:Maximum Peak Forward Surge Current (per

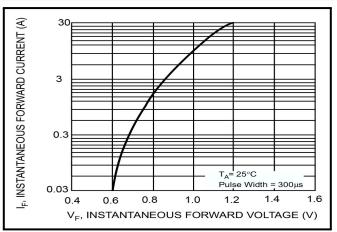


#### Figure 5:TYPICAL REVERSE CHARACTERISTICS

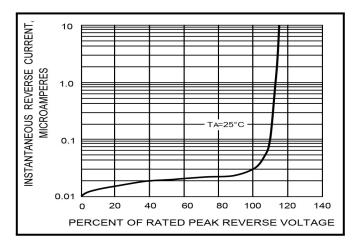


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### Figure 2: Typical Forward Characteristics (per leg)



**Figure 4: Typical Junction Capacitance** 





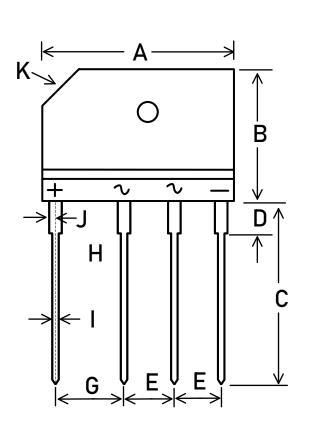


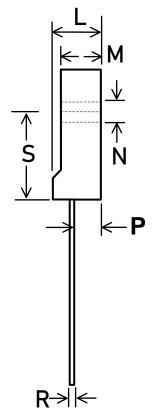


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#### **Outline Drawing -GBJ**





OVMDOL	MILLIMETER					
SYMBOL	MIN.	MAX.				
А	29.70	30.3				
В	19.70	20.3				
С	17.00	18.00				
D	3.80	4.20				
E	7.30	7.70				
G	9.80	10.20				
Н	2.00	2.40				
I	0.90	1.10				
J	2.30	2.70				
K	3.0x45°					
L	4.40	4.80				
М	3.40	3.80				
N	3.10	3.40				
Р	2.50	2.90				
R	0.60	0.80				
S	10.80	11.20				

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